

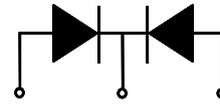


Technologies Int'l

MBRF30100CT

Features

- Low forward voltage drop
- High frequency properties and switching speed
- Guard ring for over-voltage protection



1. Anode 2. Cathode 3. Anode

TO-220F

Absolute Maximum Ratings $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{RRM}	Maximum Repetitive Reverse Voltage	100	V
V_R	Maximum DC Reverse Voltage	100	V
$I_{F(AV)}$	Maximum Average Rectified Current @ $T_C = 120^\circ\text{C}$	30	A
I_{FSM}	Maximum Forward Surge Current (per diode) 60Hz Single Half-Sine Wave	150	A
T_J, T_{STG}	Operating Junction and Storage Temperature	-40 to +175	$^\circ\text{C}$

Thermal Characteristics

Symbol	Parameter	Value	Units
$R_{\theta JC}$	Maximum Thermal Resistance, Junction to Case (per diode)	2.0	$^\circ\text{C}/\text{W}$

Electrical Characteristics (per diode)

Symbol	Parameter	Value	Units
V_{FM}^*	Maximum Instantaneous Forward Voltage $I_F = 15\text{A}$	$T_C = 25^\circ\text{C}$ 0.9	V
I_{RM}^*	Maximum Instantaneous Reverse Current @ rated V_R	$T_C = 25^\circ\text{C}$ $T_C = 125^\circ\text{C}$ 0.2 5	mA

* Pulse Test: Pulse Width=300 μs , Duty Cycle=2%

Typical Characteristics

Figure 1
Typical Forward Characteristics

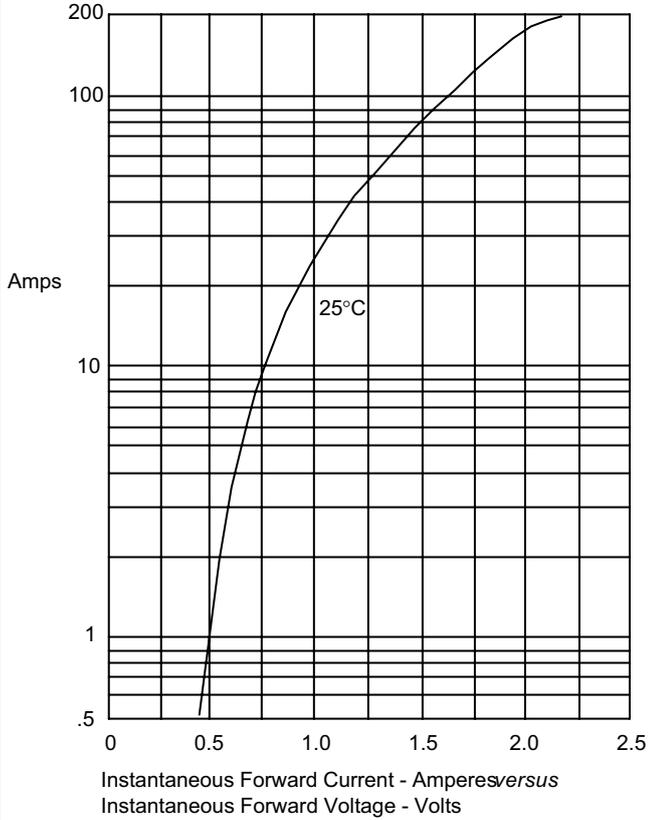


Figure 2
Typical Reverse Characteristics

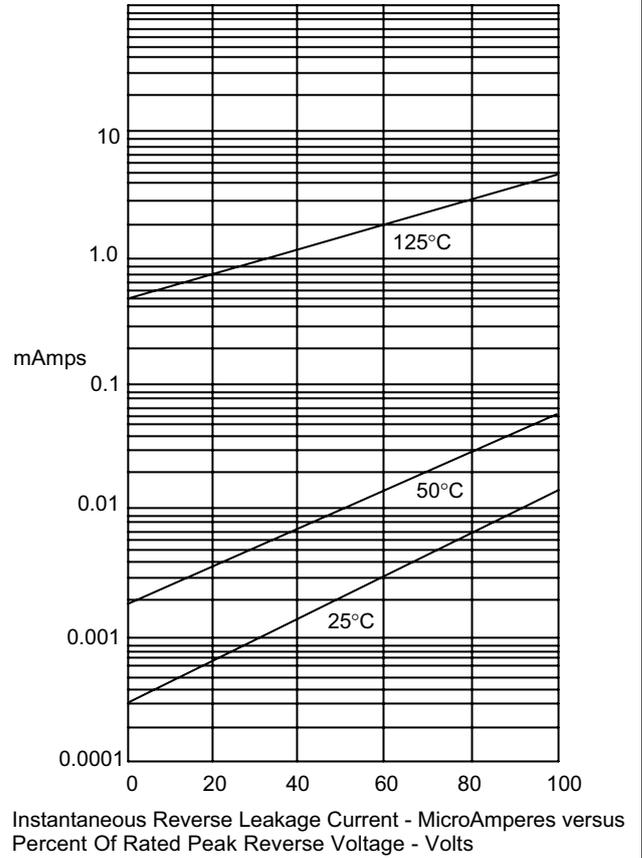


Figure 3
Forward Current Derating Curve

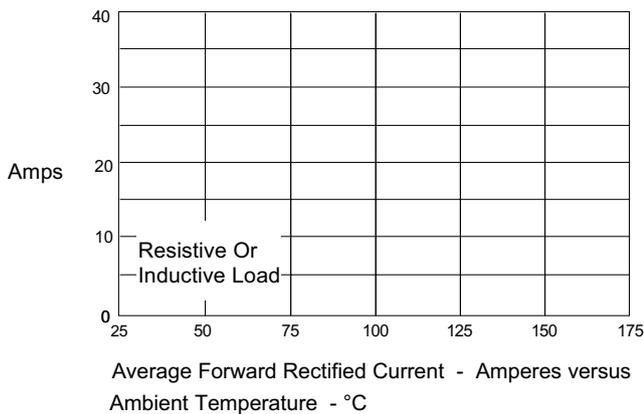
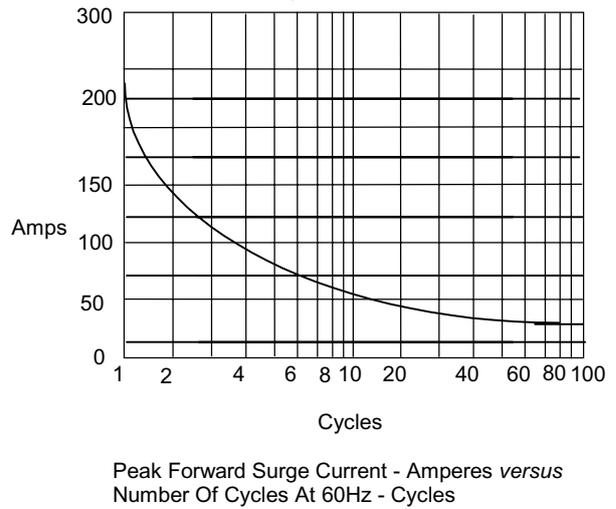
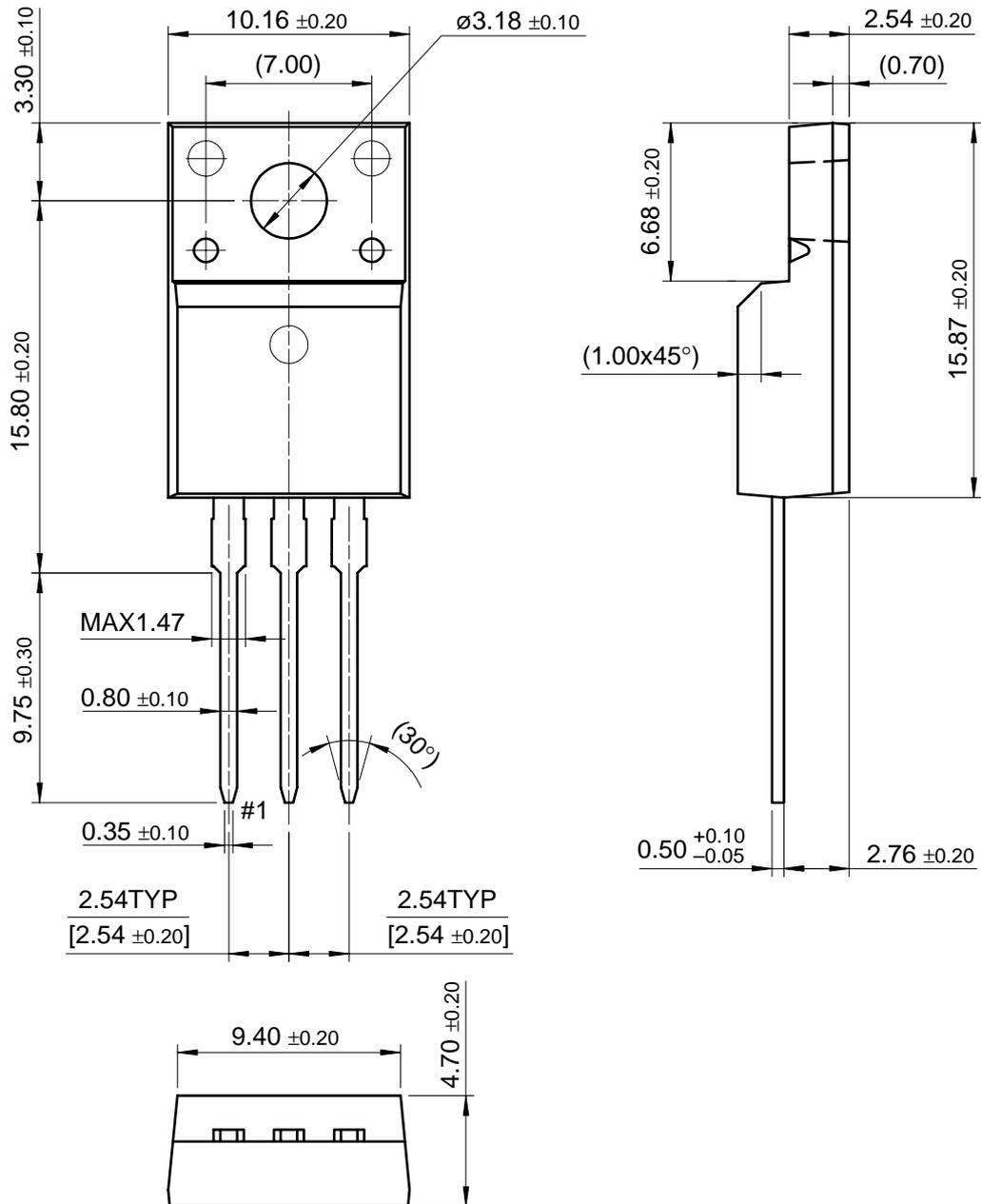


Figure 4
Peak Forward Surge Current



Package Dimension

TO-220F



Dimensions in Millimeters